

SCHOTTKY BARRIER DIODE

FEATURES

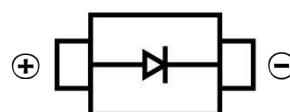
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Low forward voltage drop
- Designed and qualified for industrial level
- Surface Mount device



SMA

MECHANICAL DATA

- Case: SMA(DO-214AC)
- Case Material: Molded Plastic. UL flammability
- Classification Rating: 94V-0
- Weight: 0.065 grams (approximate)
- Marking: 10MQ060



MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	DC	1	A
V_{RRM}		60	V
I_{FSM}	$t_p = 5 \mu s$ sine	40	A
V_F	$1.5 A_{pk}$, $T_J = 125^\circ C$	0.63	V
T_J	Range	- 55 to 150	$^\circ C$

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-10MQ060-M3	UNITS
Maximum DC reverse voltage	V_R	60	V
Maximum working peak reverse voltage	V_{RWM}		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 4	I _{F(AV)}	50 % duty cycle at T _L = 120 °C, rectangular waveform On PC board 9 mm ² island (0.013 mm thick copper pad area)		1.5	A
		50 % duty cycle at T _L = 129 °C, rectangular waveform On PC board 9 mm ² island (0.013 mm thick copper pad area)		1	
Maximum peak one cycle non-repetitive surge current See fig. 6	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	40	A
		10 ms sine or 6 ms rect. pulse		10	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 4 mH		2.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T _J , maximum V _A = 1.5 x V _R typical		1.0	A

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	1 A	T _J = 25 °C	0.63	V
		1.5 A		0.71	
		1 A	T _J = 125 °C	0.57	
		1.5 A		0.63	
Maximum reverse leakage current See fig. 2	I _{RM}	T _J = 25 °C	V _R = Rated V _R	0.5	mA
		T _J = 125 °C		7.5	
Threshold voltage	V _{F(TO)}	T _J = T _J maximum		0.45	V
Forward slope resistance	r _t			86.8	mΩ
Typical junction capacitance	C _T	V _R = 10 V _{DC} , T _J = 25 °C, test signal = 1 MHz		31	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/μs

Note

⁽¹⁾ Pulse width = 300 μ s, duty cycle = 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	$T_J^{(1)}, T_{Stg}$		- 55 to 150	$^{\circ}\text{C}$
Maximum thermal resistance, junction to ambient	R_{thJA}	DC operation	80	$^{\circ}\text{C/W}$
Approximate weight			0.07	g
			0.002	oz.
Marking device		Case style SMA (similar D-64)	1H	

Note

⁽¹⁾ $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

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Typical Characteristics

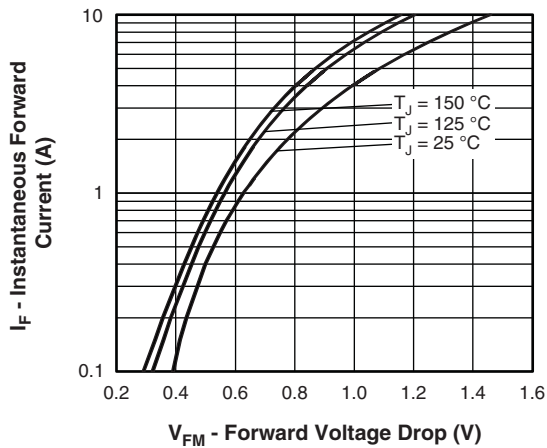


Fig. 1 - Maximum Forward Voltage Drop Characteristics

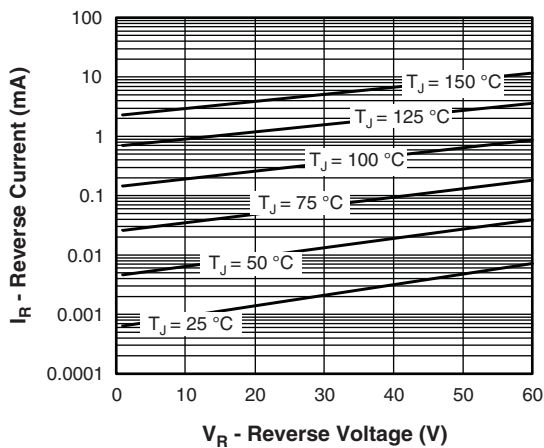


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

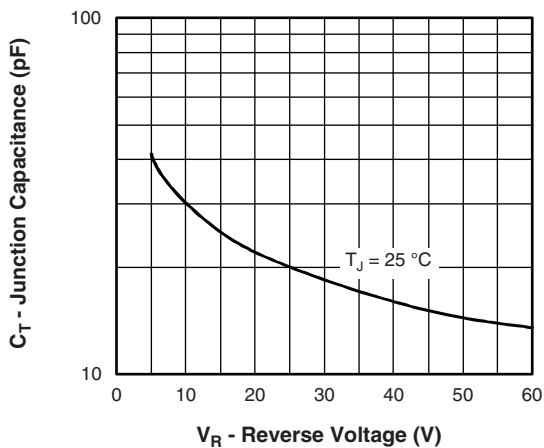


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

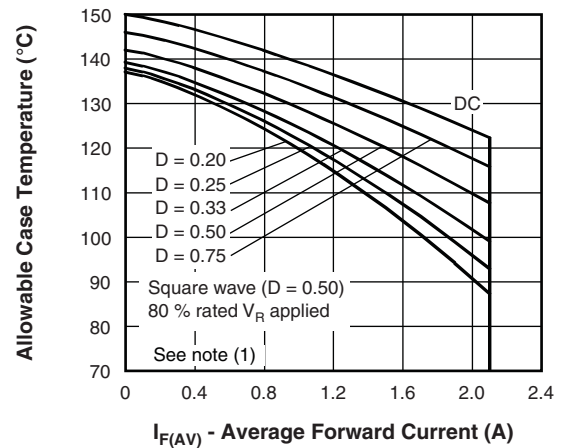


Fig. 4 - Maximum Average Forward Current vs. Allowable Lead Temperature

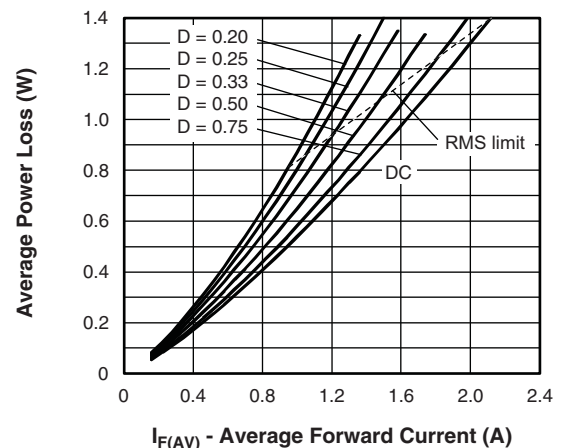


Fig. 5 - Maximum Average Forward Dissipation vs. Average Forward Current

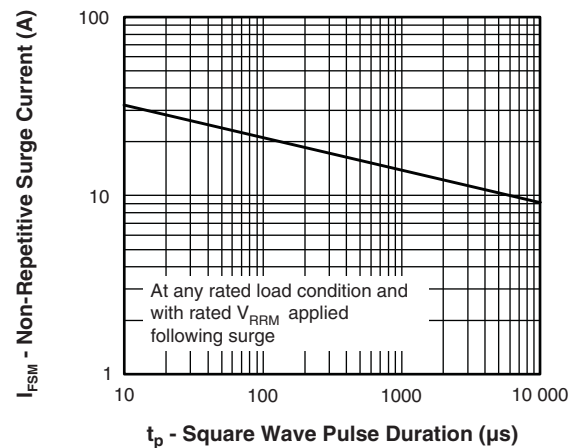


Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

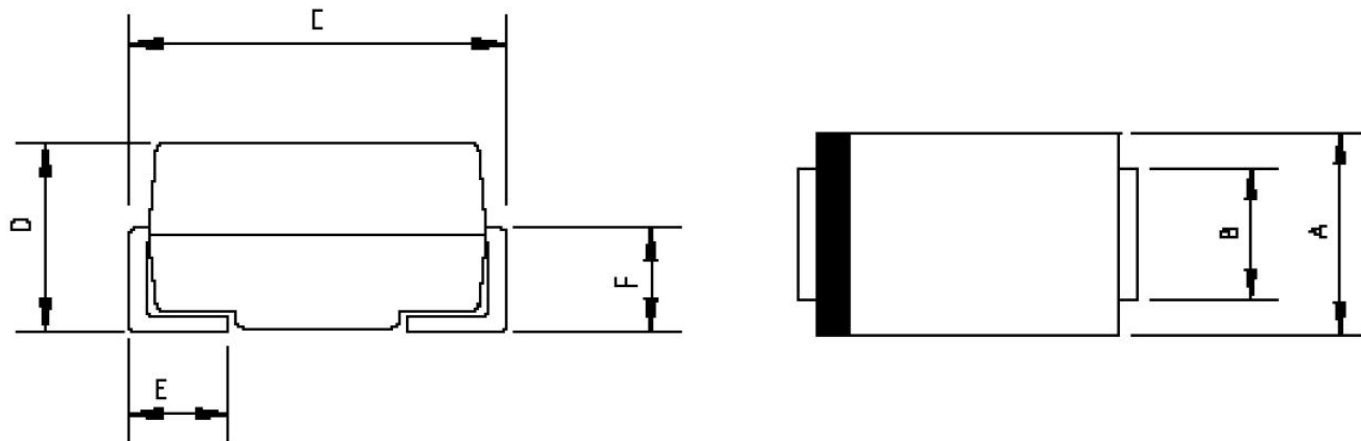
Note

(1) Formula used: $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$;

P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); P_{dREV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80\%$ rated V_R

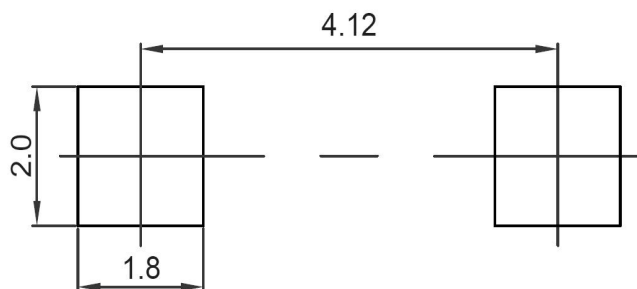
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SMA Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.20	2.80	0.086	0.110
B	1.30	1.70	0.051	0.067
C	4.70	5.30	0.185	0.209
D	1.70	2.55	0.067	0.100
E	0.90	1.50	0.035	0.059
F	0.90	1.50	0.035	0.059

SMA Suggested Pad Layout



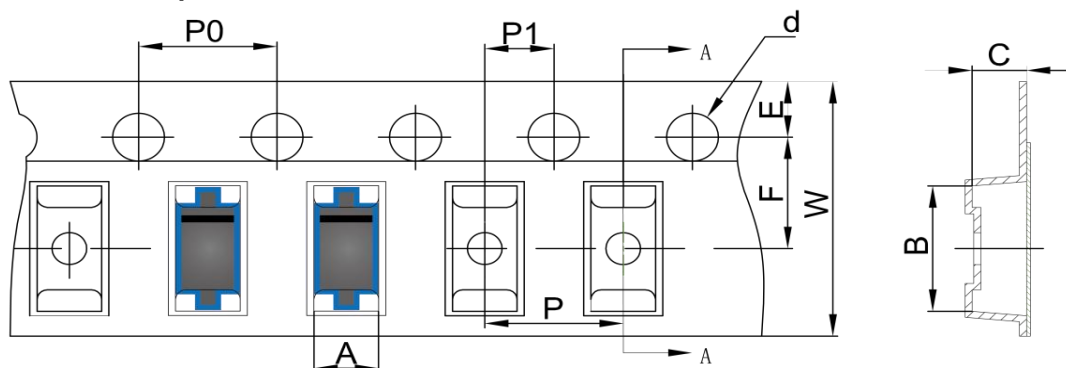
Note:

1. Controlling dimension: in millimeters
2. General tolerance: $\pm 0.05\text{mm}$
3. The pad layout is for reference purposes only

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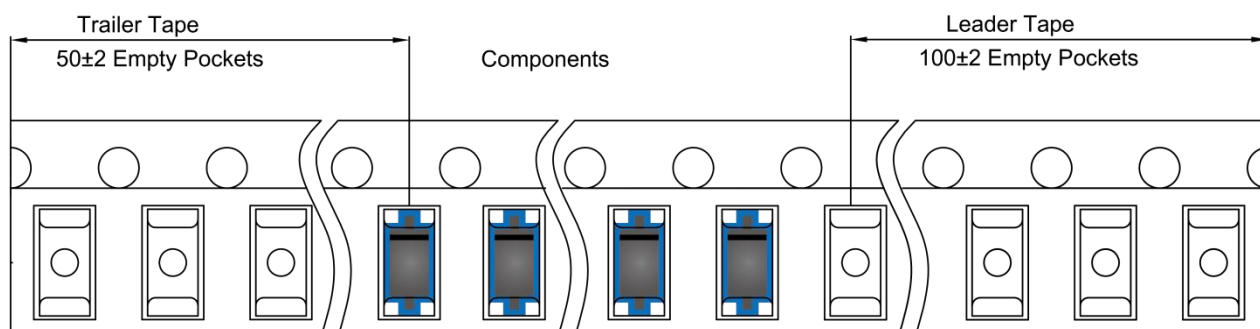
SMA Tape and Reel

SMA Embossed Carrier Tape

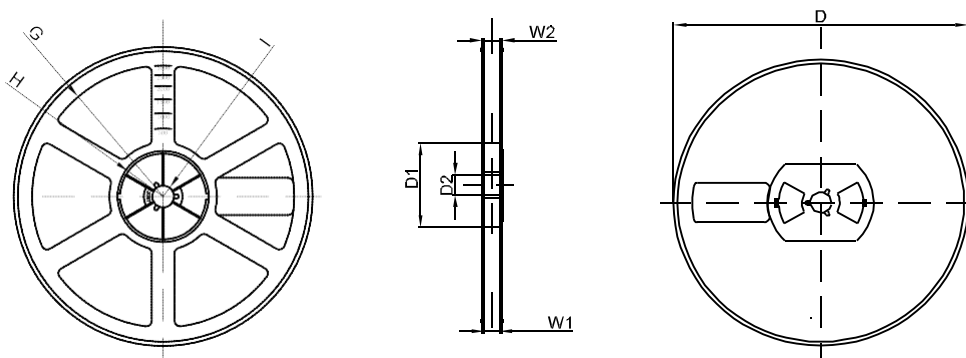


DIMENSIONS ARE IN MILLIMETER										
TYPE	A	B	C	d	E	F	P0	P	P1	W
SMA	2.89	5.35	2.68	Ø1.50	1.75	5.50	4.00	4.00	2.00	12.00
TOLERANCE	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1

SMA Tape Leader and Trailer



SMA Reel



DIMENSIONS ARE IN MILLIMETER								
REEL OPTION	D	D1	D2	G	H	I	W1	W2
7" DIA	Ø178	54.40	13.00	R78	R25.60	R6.50	12.40	17.60
TOLERANCE	±2	±1	±1	±1	±1	±1	±1	±1